

# isc N-Channel MOSFET Transistor

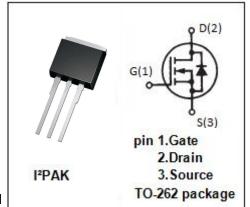
# AOW11S60

## FEATURES

- Drain Current –I\_D= 11A@ T\_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-: V<sub>DSS</sub>= 600V(Min)
- Static Drain-Source On-Resistance
- : R<sub>DS(on)</sub> = 0.399 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.



# ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	600	V				
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V				
ID	Drain Current-Continuous	11	A				
I <sub>DM</sub>	Drain Current-Single Pluse	45	A				
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	178	W				
TJ	Max. Operating Junction Temperature	-55~150	°C				
T <sub>stg</sub>	Storage Temperature	-55~150	°C				

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	m	m
DIM	MIN	MAX
A	1	0
В	6.6	6.8
C	15.23	15.25
D	10.15	10.17
F	0.76	0.78
G	1.26	1.28
Н	1.4	1.6
J	1.33	1.35
K	0.4	0.6
L	4.6	4.8
0	8.69	8.71
R	5.28	5.30
S	1.26	1.28
U	0.0	0.2
V	0.37	0.39
W	2.80	2.82

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.7	°C/W

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## <sup>1</sup> *isc & iscsemi* is registered trademark



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### **ELECTRICAL CHARACTERISTICS**

#### T<sub>c</sub>=25℃ unless otherwise specified

SYMBO L	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 5V; I <sub>D</sub> = 0.25mA	2.8		4.1	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 3.8A			0.399	Ω
lgss	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0			1	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 5.5A; V <sub>GS</sub> = 0		0.84		V

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